

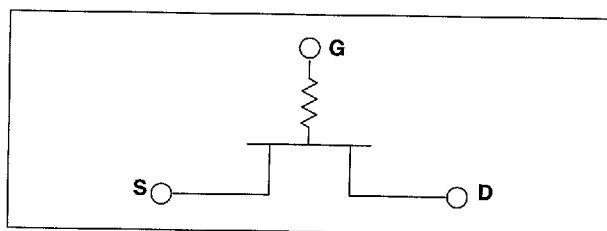
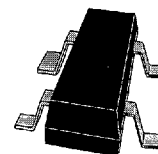
# GaAs MMIC Control FET in SOT 143 DC-2.5 GHz



AF002C1-32

## Features

- Low Cost
- Small SOT 143 Package
- Series or Shunt Configuration
- Low DC Current Drain
- Ideal Switch Building Block



## Description

The AF002C1-32 consists of a single GaAs switching FET that can be used in both series and shunt configurations. A positive control voltage may be used by simply adding 3 DC blocking capacitors.

Isolation performance degrades at higher frequencies due to package parasitics. These parasitics can be tuned out in narrow band applications as shown in a AF002C1-39 data sheet.

## Absolute Maximum Ratings

RF Input Power:	2W > 500 MHz 0/-8V
	0.5W @ 50 MHz 0/-8V
Control Voltage:	+0.2V, -10V
Operating Temperature:	-40°C to 85°C
Storage Temperature:	-65°C to 150°C
Θ <sub>JC</sub> :	25°C/W

Note: Exceeding these parameters may cause irreversible damage.

## Operating Characteristics at 25°C

Switching Characteristics			
RISE, FALL (10/90% or 90/10% RF)	3	ns	Typ
ON, OFF (50% CTL to 90/10% RF)	6	ns	Typ
Input Power for 1 dB Compression			
Control Voltages (Vdc)	0/-5	0/-8	
0.5-2.0 GHz	+20	24	dBm Typ
Control Voltages			
V <sub>0</sub> (Low)	0 to -0.2V @ 20 μA Max		
V <sub>0</sub> (High)	-5V @ 50 μA to -9V @ 200 μA Max		

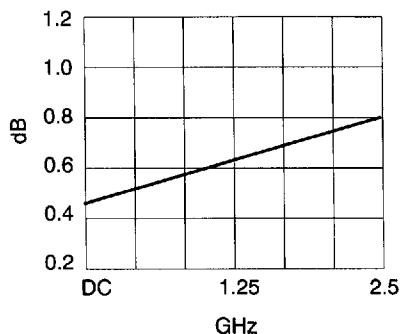
## Electrical Specifications at 25°C

R <sub>ON</sub> <sup>1</sup>	C <sub>OFF</sub> <sup>2</sup>	Insertion Loss 1 GHz <sup>3,4</sup>	
		Series	Shunt
6.4	0.13	0.7 dB	0.2

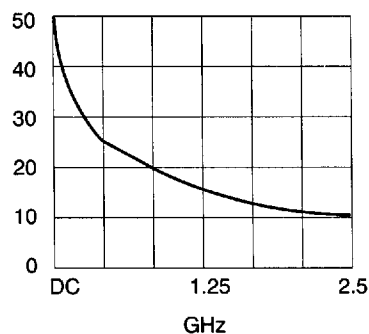
1. R<sub>ON</sub> - Resistance in ohms in low impedance state when '0' Volts is applied on Gate (G).
2. C<sub>OFF</sub> - Capacitance (FET) in pF in high impedance state when -5V is applied on Gate (G).
3. Package inductance is 3 nH, package capacitance is 0.17 pf.
4. Insertion loss changes by 0.003 dB/°C.

### Typical Performance Data

Series Configuration (Not Tuned)

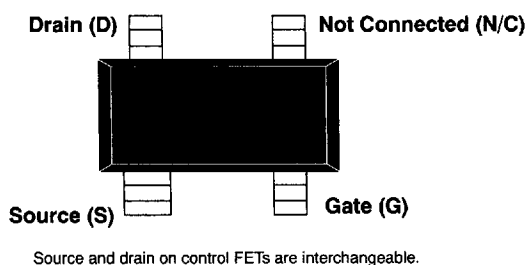


Insertion Loss vs. Frequency



Isolation vs. Frequency

### Pin Out

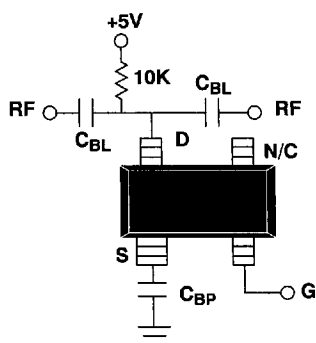


### Truth Table (Negative Voltage Operation)

Shunt			
S	D	G	State
GND	RF	-5	Insertion Loss
		0	Isolation
Series			
RF	RF	-5	Isolation
		0	Insertion Loss

### Positive Voltage Operation

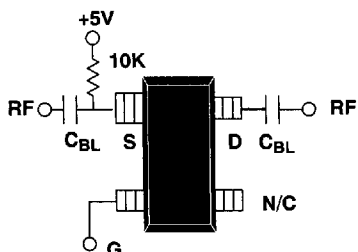
#### Shunt



### Truth Table (Positive Voltage Operation)

Shunt			
S	D	G	State
GND	RF	0	Insertion Loss
		+5	Isolation
Series			
RF	RF	0	Isolation
		+5	Insertion Loss

#### Series



C<sub>BL</sub>, C<sub>BP</sub> - Choose value for low impedance at desired operating frequency.

# RF GaAs MMIC Products in Metal Packages

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